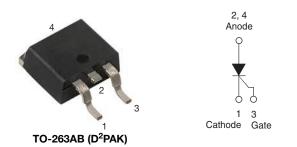


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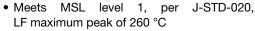
Vishay Semiconductors

Thyristor High Voltage Surface Mount Phase Control SCR, 10 A

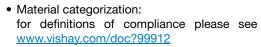


PRODUCT SUMMARY						
Package	TO-263AB (D ² PAK)					
Diode variation	Single SCR					
I _{T(AV)}	6.5 A					
V_{DRM}/V_{RRM}	800 V					
V_{TM}	< 1.15 V					
I _{GT}	15 mA					
T_J	-40 to +125 °C					

FEATURES











ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-10TTS08SPbF high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper	2.5	3.5						
Aluminum IMS, R _{thCA} = 15 °C/W	6.3	9.5	A					
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	14.0	18.5						

Note

• T_A = 55 °C, T_J = 125 °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
I _{T(AV)}	Sinusoidal waveform	6.5	A					
I _{RMS}		10	A					
V _{RRM} /V _{DRM}		800	V					
I _{TSM}		110	А					
V _T	6.5 A, T _J = 25 °C	1.15	V					
dV/dt		150	V/µs					
dl/dt		100	A/µs					
TJ	Range	-40 to +125	°C					

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
VS-10TTS08SPbF	800	800	1.0



ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum average on-state current	I _{T(AV)}	T 110 °C 100° conduc	6.5					
Maximum RMS on-state current	I _{T(RMS)}	T _C = 112 °C, 180° conduc	tion hall sine wave	10	٨			
Maximum peak, one-cycle,	1	10 ms sine pulse, rated V _I	RRM applied, T _J = 125 °C	95	Α			
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volta	age reapplied, T _J = 125 °C	110				
Maying up 12+ for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied, T _J = 125 °C		45	A ² s			
Maximum I ² t for fusing	1-1	10 ms sine pulse, no volta	10 ms sine pulse, no voltage reapplied, $T_J = 125$ °C					
Maximum l²√t for fusing	I ² √t	t = 0.1 ms to 10 ms, no vo	640	A²√s				
Maximum on-state voltage drop	V_{TM}	6.5 A, T _J = 25 °C	1.15	V				
On-state slope resistance	r _t	T 405 00		17.3	mΩ			
Threshold voltage	V _{T(TO)}	T _J = 125 °C		0.85	V			
Maximum various and divest leakers as weent	1 //	T _J = 25 °C	V Datad V A/	0.05				
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	V _R = Rated V _{RRM} /V _{DRM}	1.0				
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		30	mA			
Maximum latching current	ΙL	Anode supply = 6 V, resis	50					
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80^\circ$		V/µs				
Maximum rate of rise of turned-on current	dl/dt			100	A/μs			

TRIGGERING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak gate power	P_{GM}		8.0	W				
Maximum average gate power	P _{G(AV)}		2.0	VV				
Maximum peak positive gate current	+I _{GM}		1.5	Α				
Maximum peak negative gate voltage	-V _{GM}		10	V				
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA				
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	15					
		Anode supply = 6 V, resistive load, T _J = 125 °C	10					
		Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2					
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	V				
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V				
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V Detectively	0.2					
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	0.1	mA				

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8	
Typical reverse recovery time	t _{rr}	T = 105 °C	3	μs
Typical turn-off time	t _q	T _J = 125 °C	100	

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS								
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C					
Soldering temperature	T _S	For 10 s (1.6 mm from case)	260						
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5	°C/W					
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	C/VV					
Approximate weight			2	g					
Approximate weight			0.07	OZ.					
Marking device		Case style D ² PAK (SMD-220)	10TTS	08S					

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

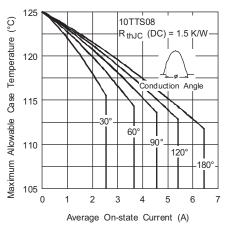


Fig. 1 - Current Rating Characteristics

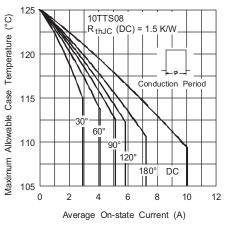


Fig. 2 - Current Rating Characteristics

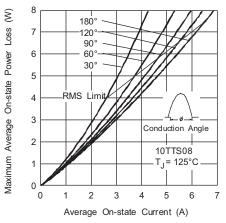


Fig. 3 - On-State Power Loss Characteristics

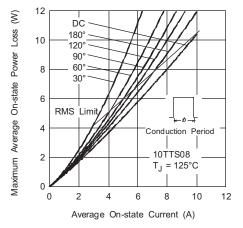


Fig. 4 - On-State Power Loss Characteristics

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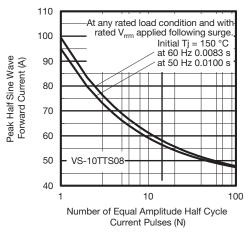


Fig. 5 - Maximum Non-Repetitive Surge Current

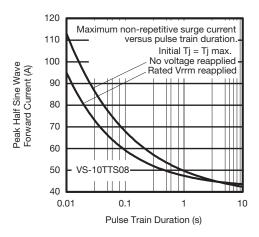


Fig. 6 - Maximum Non-Repetitive Surge Current

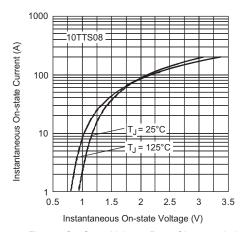


Fig. 7 - On-State Voltage Drop Characteristics

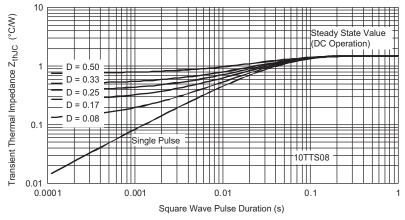
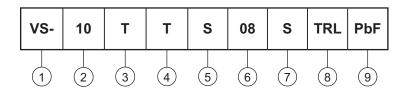


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating, RMS value
- 3 Circuit configuration:

T = single thyristor

4 - Package:

T = TO-220AC

5 - Type of silicon:

S = converter grade

- Voltage code x 100 = V_{RRM}
- 7 S = TO-220 D²PAK (SMD-220) version
- 8 Tape and reel option:
 - TRL = tape and reel (left oriented)
 - TRR = tape and reel (right oriented)
- 9 PbF = lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-10TTS08SPbF	50	1000	Antistatic plastic tubes					
VS-10TTS08STRRPbF	800	800	13" diameter reel					
VS-10TTS08STRLPbF	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95046</u>					
Part marking information	www.vishay.com/doc?95054				
Packaging information	www.vishay.com/doc?95032				



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	ETERS	INC	HES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.		STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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